# NTS10120EMFS, NRVTS10120EMFS

# **Very Low Leakage Trench-based Schottky Rectifier**

# Features

- Fine Lithography Trench-based Schottky Technology for Very Low Forward Voltage and Low Leakage
- Fast Switching with Exceptional Temperature Stability
- Low Power Loss and Lower Operating Temperature
- Higher Efficiency for Achieving Regulatory Compliance
- Low Thermal Resistance
- High Surge Capability
- NRV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These are Pb–Free and Halide–Free Devices

# **Typical Applications**

- Switching Power Supplies including Notebook / Netbook Adapters, ATX and Flat Panel Display
- High Frequency and DC–DC Converters
- Freewheeling and OR-ing Diodes
- Reverse Battery Protection
- LED Lighting
- Instrumentation

# **Mechanical Characteristics:**

- Case: Epoxy, Molded
- Epoxy Meets Flammability Rating UL 94–0 @ 0.125 in.
- Lead Finish: 100% Matte Sn (Tin)
- Lead and Mounting Surface Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- Device Meets MSL 1 Requirements



# **ON Semiconductor®**

http://onsemi.com

# TRENCH SCHOTTKY RECTIFIERS **10 AMPERES 120 VOLTS**





- = Work Week
- ΖZ = Lot Traceability

# **ORDERING INFORMATION**

Device	Package	Shipping†
NTS10120EMFST1G	SO–8 FL (Pb–Free)	1500 / Tape & Reel
NTS10120EMFST3G	SO–8 FL (Pb–Free)	5000 / Tape & Reel
NRVTS10120EMFST1G	SO–8 FL (Pb–Free)	1500 / Tape & Reel
NRVTS10120EMFST3G	SO–8 FL (Pb–Free)	5000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

# NTS10120EMFS, NRVTS10120EMFS

# MAXIMUM RATINGS

Rating	Symbol	Value	Unit	
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	120	V	
Average Rectified Forward Current (Rated $V_R$ , $T_C$ = 165°C)	I <sub>F(AV)</sub>	10	A	
Peak Repetitive Forward Current, (Rated $V_R$ , Square Wave, 20 kHz, $T_C$ = 163°C)	I <sub>FRM</sub>	20	A	
Non–Repetitive Peak Surge Current (Surge Applied at Rated Load Conditions Halfwave, Single Phase, 60 Hz)	I <sub>FSM</sub>	200	A	
Storage Temperature Range	T <sub>stg</sub>	-65 to +175	°C	
Operating Junction Temperature	TJ	-55 to +175	°C	
Unclamped Inductive Switching Energy (10 mH Inductor, Non-repetitive)	E <sub>AS</sub>	100	mJ	
ESD Rating (Human Body Model)		3B		
ESD Rating (Machine Model)		M4		

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

# THERMAL CHARACTERISTICS

Characteristic	Symbol	Тур	Max	Unit
Thermal Resistance, Junction-to-Case, Steady State (Assumes 600 mm <sup>2</sup> 1 oz. copper bond pad, on a FR4 board)	$R_{ extsf{ heta}JC}$	1.8	-	°C/W

## **ELECTRICAL CHARACTERISTICS**

Rating	Symbol	Тур	Мах	Unit
Instantaneous Forward Voltage (Note 1)	V <sub>F</sub>			V
$(I_{F} = 5 \text{ A}, T_{J} = 25^{\circ}\text{C})$		0.6	-	
$(I_F = 10 \text{ A}, T_J = 25^{\circ}\text{C})$		0.735	0.82	
$(I_F = 5 \text{ A}, T_J = 125^{\circ}\text{C})$		0.515	-	
$(I_F = 10 \text{ A}, T_J = 125^{\circ}\text{C})$		0.588	0.63	
Instantaneous Reverse Current (Note 1)	I <sub>R</sub>			
$(V_R = 90 V, T_J = 25^{\circ}C)$		1.0	-	μΑ
(Rated dc Voltage, $T_J = 25^{\circ}C$ )		3.75	30	μΑ
$(V_R = 90 \text{ V}, \text{ T}_J = 125^{\circ}\text{C})$		2.0	-	mA
(Rated dc Voltage, $T_J = 125^{\circ}C$ )		3.1	20	mA

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 1. Pulse Test: Pulse Width =  $300 \ \mu$ s, Duty Cycle  $\leq 2.0\%$ .

# NTS10120EMFS, NRVTS10120EMFS

#### 100 100 iF, INSTANTANEOUS FORWARD i<sub>F</sub>, INSTANTANEOUS FORWARD CURRENT (A) L 01 T<sub>A</sub> = 125°C T<sub>A</sub> = 125°C CURRENT (A) = 150°C TΑ TA = 150°C 175°C = T<sub>A</sub> = 175°C = 25°C = 25°C T<sub>Α</sub> ΙA -55°C I<sub>A</sub> = -55°C = 0.1 0.1 0.1 0.2 0.3 0.4 0.5 0.6 0.7 0.8 0.9 1.0 1.1 1.2 1.3 0.1 0.2 0.3 0.4 0.5 0.6 0.7 0.8 0.9 1.0 1.1 1.2 1.3 0 0 V<sub>F</sub>, INSTANTANEOUS FORWARD VOLTAGE (V) V<sub>F</sub>, INSTANTANEOUS FORWARD VOLTAGE (V) Figure 1. Typical Instantaneous Forward Figure 2. Maximum Instantaneous Forward Characteristics Characteristics () 1.E+00 1.E-01 (¥) 1.E+00 1.E-01 1.E-02 1.E-02 1.E-03 1.E-04 1.E-05 1.E-05 1.E-07 1.E-07 T<sub>A</sub> = 175°C 150 T<sub>A</sub> = 175°C T<sub>A</sub> = 125°C O III 1.E-02 III 1.E-03 III 1.E-03 III 1.E-03 III 1.E-03 III 1.E-04 III 1.E-05 III 1.E-06 T<sub>A</sub> = 150°C T<sub>A</sub> = 125°C T<sub>A</sub> = 25°C T<sub>A</sub> = 25°C 's .E-07 90 100 110 120 <sub>ຜ</sub>ີ 90 100 110 120 0 20 30 40 50 60 70 80 0 10 20 30 40 50 60 70 80 10 Ŕ V<sub>R</sub>, INSTANTANEOUS REVERSE VOLTAGE (V) V<sub>R</sub>, INSTANTANEOUS REVERSE VOLTAGE (V) Figure 3. Typical Reverse Characteristics **Figure 4. Maximum Reverse Characteristics** I<sub>F(AV)</sub>, AVERAGE FORWARD CURRENT (A) 10,000 25 T<sub>J</sub> = 25°C $R_{\theta JC} = 1.8^{\circ}C/W$ C, JUNCTION CAPACITANCE (pF) 20 1000 DC 15 Square Wave 10 100 5 10 0 120 100 110 130 140 150 160 170 0.1 10 1 V<sub>R</sub>, REVERSE VOLTAGE (V) T<sub>C</sub>, CASE TEMPERATURE (°C)

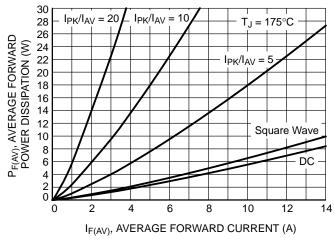
# **TYPICAL CHARACTERISTICS**

Figure 5. Typical Junction Capacitance

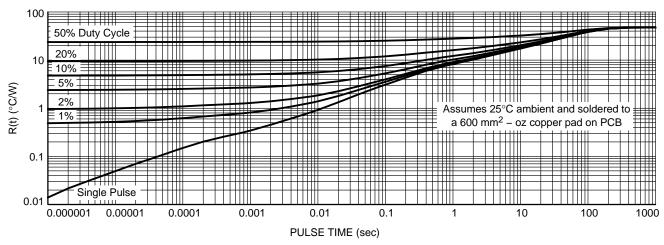
http://onsemi.com 3 Figure 6. Current Derating

# NTS10120EMFS, NRVTS10120EMFS

# **TYPICAL CHARACTERISTICS**









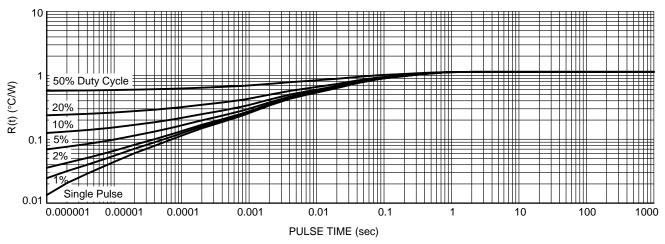


Figure 9. Typical Transient Thermal Response Characteristics, Junction-to-Case





onsemi, ONSEMI, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does **onsemi** assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using **onsemi** products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by **onsemi**. "Typical" parameters, including "Typicals" must be provided in **onsemi** data sheets and/or specifications can and do vary in different applications and calcula performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. **onsemi** does not convey any license under any of its intellectual property rights nor the rights of others. **onsemi** products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use **onsemi** products for any such unintended or unauthorized application, Buyer shall indemnify and hold **onsemi** and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that **onsemi** was negligent regarding the design or manufacture of the part. **onsemi** is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

#### PUBLICATION ORDERING INFORMATION

#### LITERATURE FULFILLMENT:

### TECHNICAL SUPPORT

onsemi Website: www.onsemi.com

Email Requests to: orderlit@onsemi.com

North American Technical Support: Voice Mail: 1 800-282-9855 Toll Free USA/Canada Phone: 011 421 33 790 2910

Europe, Middle East and Africa Technical Support: Phone: 00421 33 790 2910 For additional information, please contact your local Sales Representative